TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA8161F

DC / DC Converter System IC For Power Supply

The TA8161F is a DC / DC converter system IC, which is developed for supplying a voltage (for 2.5V or 5V) for CMOS IC

It is especially suitable for low voltage operation, and for power supply and back-up of speech recording / playback LSls, with only one or two dry batteries.

Features

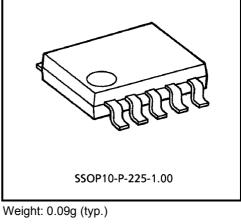
- Output voltage can be switched over to 2.5V or 5V $V_O = 2.5V$ mode (by one dry-battery) $V_O = 5V$ mode (by one or two dry-batteries)
- Built-in backup mode with a very low power dissipation

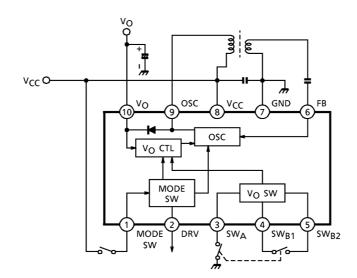
$$\begin{split} &V_{CC} = 1.2 V, \, T_{a} = 25^{\circ}C, \, I_{O} = 0 \\ &I_{CC1} = 50 \mu A \, (typ.)..... \, V_{O} = 5 V \, \, mode \\ &I_{CC2} = 30 \mu A \, (typ.)..... \, V_{O} = 2.5 V \, \, mode \end{split}$$

- Built-in mode switch (back up mode / power supply mode)
- Excellent power efficiency, by blocking oscillation
- Output current (V_{CC} = 1.2V, Ta = 25°C) $I_{O1} = 11 \text{mA (typ.)}...... V_{O} = 5 \text{V mode}$ $I_{O2} = 22 \text{mA (typ.)}...... V_O = 2.5 \text{V mode}$
- Operating supply voltage range (Ta = 25°C) $V_{CC2 (opr)} = 0.9 \sim 4V (V_O = 5V \text{ mode})$

 $V_{CC1 (opr)} = 0.9 \sim 2.2 V (V_O = 2.5 V \text{ mode})$

Block Diagram





Terminal Explanation

Terminal			Function	Internal Circuit				
No.	Name		Function		internal Gircuit			
1	Mode SW	Mode switch V _{CC} : Power supply GND / OPEN: Back	mode k up mode	V () ()				
2	DRV	Current driver This terminal can b because it is synch In case that this cir should be connecte terminal, as a resul improved.	ronized with mode cuit isn't used, this ed with SW _{B2} (pin	e switch. s terminal (5))	Mode sw			
3	SW _A	Change-over switc	ch of output voltag	e. 1	10 - 0 v ₀			
	SW _{B1}		SW _{1a}	SW _{1b}	sw _{1a} "			
4		5V mode	OPI	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				
		2.5V mode	Sho	ort	\$ \$ 4 y sw _{1b}			
5	SW _{B2}	To prevent parasitic capacitor should be and V _{CC} . Because impedance.	e connected betwe	en SW _{B1}	5 5			
6	FB							
9	OSC	Flyback converter			Vcc 9 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0			
10	Vo							
7	GND		_		_			
8	V _{CC}		_		_			

Application Note

1. Mode explanation

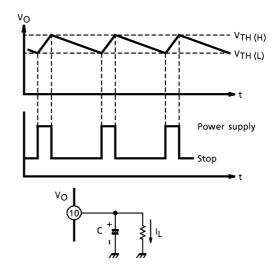
IC Mode		V _O SW		Mode SW	Current Driver	
		SW _{1A}	SW _{1B}	SW ₂	Pin(2)	
V _O = 2.5V	Power supply mode	GND	Short	V _{CC}	ON	
V() = 2.5V	Back up mode	GND	Short	OPEN / GND	OFF	
V _O = 5V	Power supply mode	OPEN	OPEN	V _{CC}	ON	
	Back up mode	OFEN	OFEN	OPEN / GND	OFF	

2. Operation of back up mode

In case of back up mode, this IC is operated by blocking oscillation. This operation is described as follows.

- (1) When potential of output VO reaches VTH (L), the VO control circuit in the IC starts the converter circuit.
- (2) When the converter is started, the capacitor C connected with VO terminal is charged and when VO reaches VTH (H), the converter is stopped.
- (3) The charge of the capacitor C is consumed gradually by load current and comes close to VTH (L). This IC is performs the blocking oscillation by repeating (1) \sim (3) above. The frequency of this blocking oscillation depends

The frequency of this blocking oscillation depends on load current and a capacitor connected with V_O terminal.



3. Mode SW

It is necessary to connect an external pull-down resistor with the terminal of MODE SW (pin(1)), in case that this IC operates in power supply mode due to external noise etc, even though this IC is back up mode.

4. Current driver terminal

In case that current driver terminal (pin(2)) isn't used, this terminal should be connected with SWB2 terminal (pin(5)), as a result low voltage operation is improved. When this terminal is kept open, there is a probability that the MODE SW circuit doesn't operate normally.

5. Radiation

It is necessary to connect a L / C or R / C filter, in case that output noise is large due to radiation etc. Because this IC has adopted a converter circuit of flyback system.

6. Vo and Vcc

Supply voltage shoule not be high than output voltage, because this IC is boost type DC / DC converter.

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Supply voltage	V _{CC}	5	V
Output voltage	Vo	8	V
Output current	ΙO	40	mA
Power dissipation	P _D (Note)	400	mW
Operating temperature	T _{opr}	-25~75	°C
Storage temperature	T _{stg}	−55~150	°C

(Note) Derated above Ta = 25° C in the proportion of 3.2mW / $^{\circ}$ C

Electrical Characteristics

(unless otherwise specified, V_{CC} = 1.2V, Ta = 25°C, SW₂: a, SW₃: a)

	Characteristic	Symbol	Test Cir– cuit	SW ₁	Tes	t Condition	Min.	Тур.	Max.	Unit
	Quiescent supply current	I _{CCQ1}		а	I _O = 0		_	0.5	1.0	- mA
	Quiescent supply current	I _{CCQ2}		b			_	0.3	0.8	
	Boosted output voltage 1	V _{O11}			I _O = 5mA		4.6	5.0	5.3	V
		V _{O12}			$I_O = 5mA$, $V_{CC} = 1V$		4.6	5.0	5.3	v
node	V _{O1} temperature coefficient	ΔV _{O1 / T}		a _	I _O = 5mA		_	-4.4	_	mV /°C
ply r	Vo. maximum output	I _{O1 max1}			V _{CC} = 1.2V	ΔV_{O1} =0.5V,with respect to standard I_{O1} = 5mA	8	11	_	mA
Power supply mode	V _{O1} maximum output current	I _{O1 max2}	_		V _{CC} = 1.5V		10	17	_	
Po	Posted output voltage 2	V _{O21}			I _O = 10mA		2.2	2.5	2.8	.,
	Boosted output voltage 2	V _{O22}		V _{CC} = 1V, I _O = 10mA		2.2	2.5	2.8	- V	
	V _{O2} temperature coefficient	ΔV _{O2} / T		b	I _O = 10mA		_	-4.6	_	mV /°C
	V _{O2} maximum output current	I _{O2 max}			ΔV_{O2} = 0.3V, with respect to standard I _{O2} = 10mA		16	22	_	mA
	Quiescent supply current	I _{BU1}		а	SW ₂ : b, I _O = 0		_	50	_	
e Se		I _{BU2}	b		3vv2. b, 10 = 0		_	30	_	μA
Back up mode	OSC start output voltage1	V _{TH11}		a b	SW ₂ : b, I _O = 0		4.0	4.3	4.6	- V
k up	OSC stop output voltage1	V _{TH12}					4.6	5.0	5.3	
Вас	OSC start output voltage2	V _{TH21}			SW ₂ : b, I _O = 0		1.8	2.2	2.4	V
	OSC stop output voltage2	V _{TH22}					2.2	2.5	2.7	
OS0 volta	C transistor saturation age	V _{DRV}	_	b	V _{CC} = 0.9V, SW ₃ : b I _{DRV} = 0.5mA		_	50	150	mV
Mode SW	Power supply mode on current	I _{mode}	_	b	$V_{CC} = 0.9V, SW_2$: c SW ₃ : b $V_{O1} \ge 2V, V_{DRV} \le 50mV$		10	_	_	μA
Моде	Back up mode on voltage	V _{mode}	_	b	$V_{CC} = 0.9V, SW_2$: d SW ₃ : b $V_{DRV} \ge 0.8V$		0	_	0.3	V

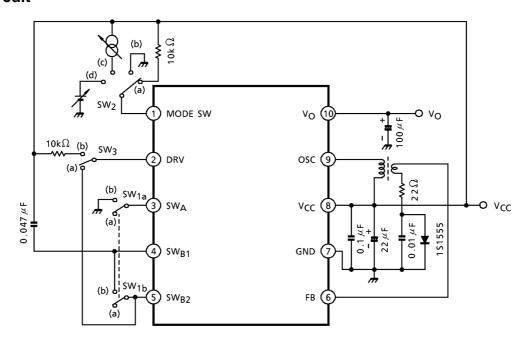
Coil Data

Test	L (µH) Q _o		Τι	ırn	Wire	Deference	
Frequency 1–3		1–3	4–6	(mm ϕ)	Reference		
796kHz	200 35		72			Sumida electric co., ltd, 6300–131A	



(Bottom of view)

Test Circuit

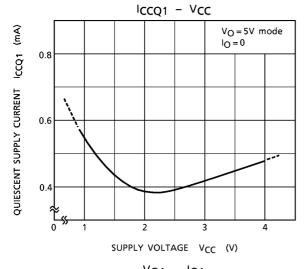


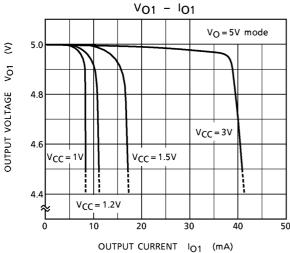
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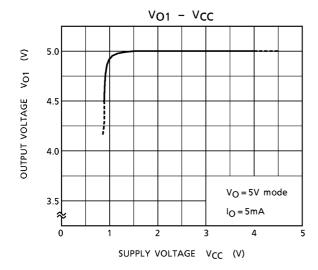
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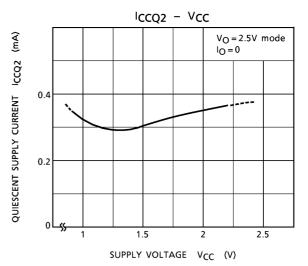
Characteristic Curves

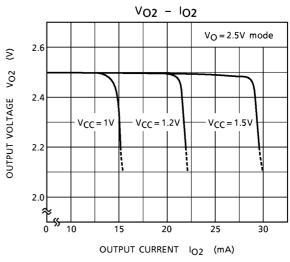
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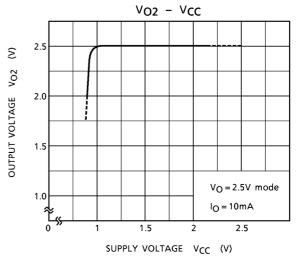




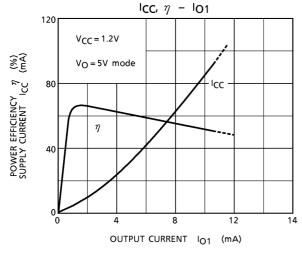


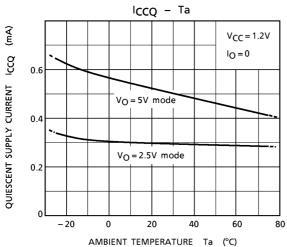


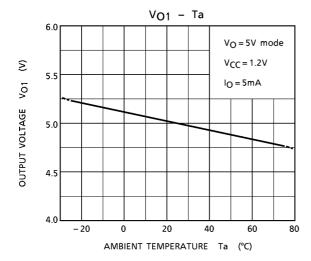


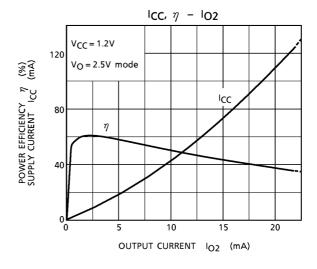


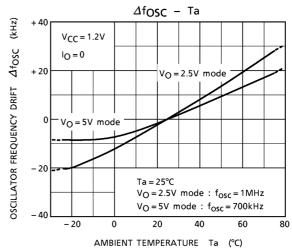
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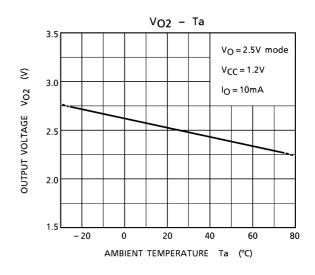








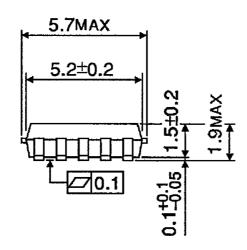


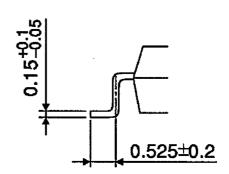


Package Dimensions

1.0

0.6TYP 0.4±0.1 0 0.20 M





Weight: 0.09g (typ.)

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